

Supporting information:

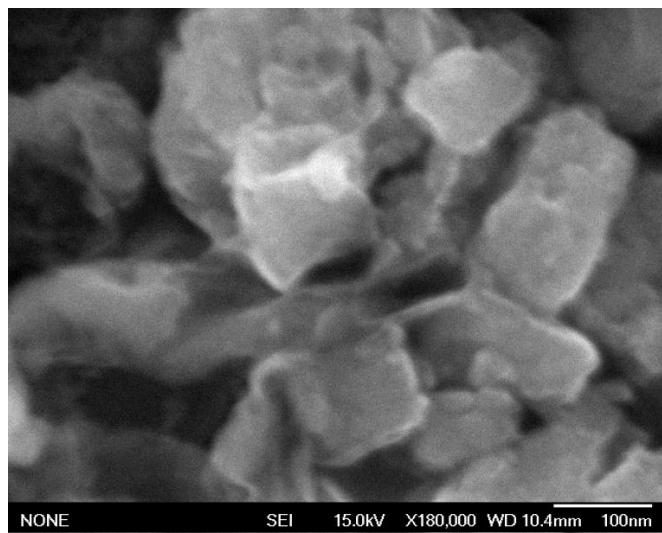


Figure S1. The morphology of the light scattering SnO_2 particles.

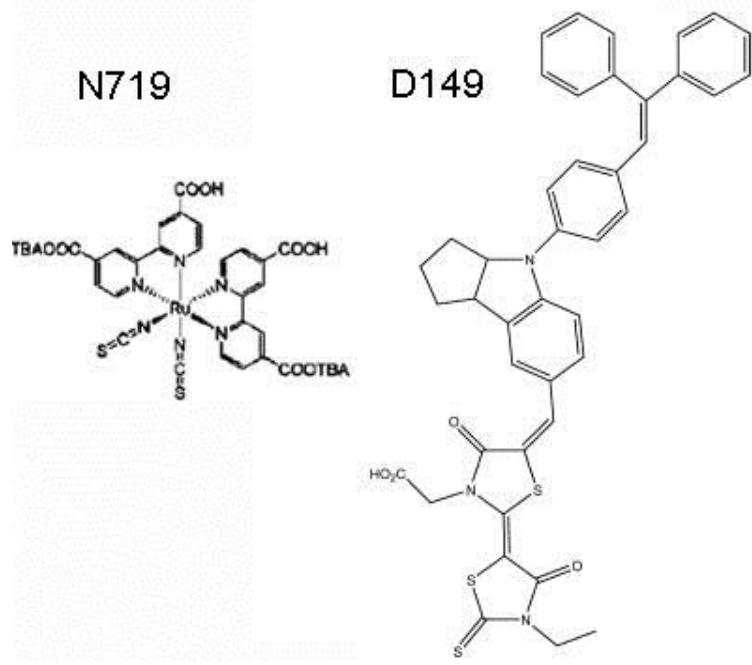


Figure S2. The chemical structures of N719 and D149.

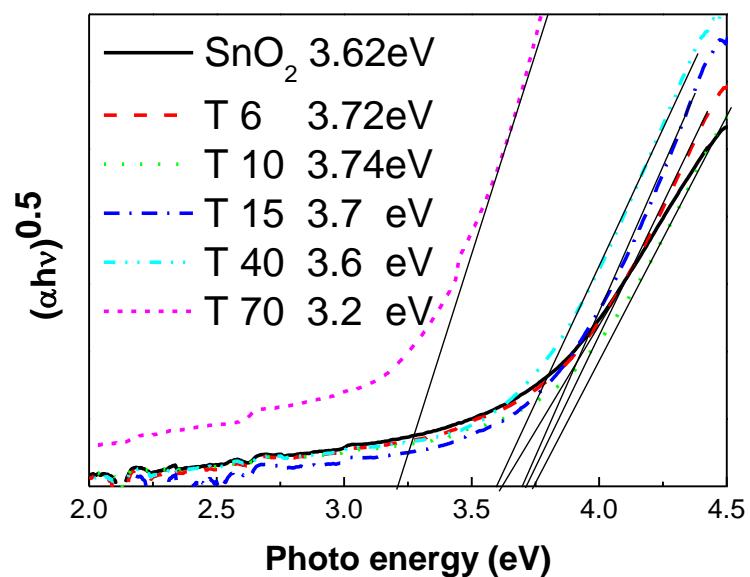


Figure S3. The curves of $(\alpha h\nu)^{\frac{1}{2}}$ versus Photo energy (eV) of $\text{Ti}_x\text{Sn}_{1-x}\text{O}_2$ photoanodes, the inset indicates the obtained indirect optical band gap energy.

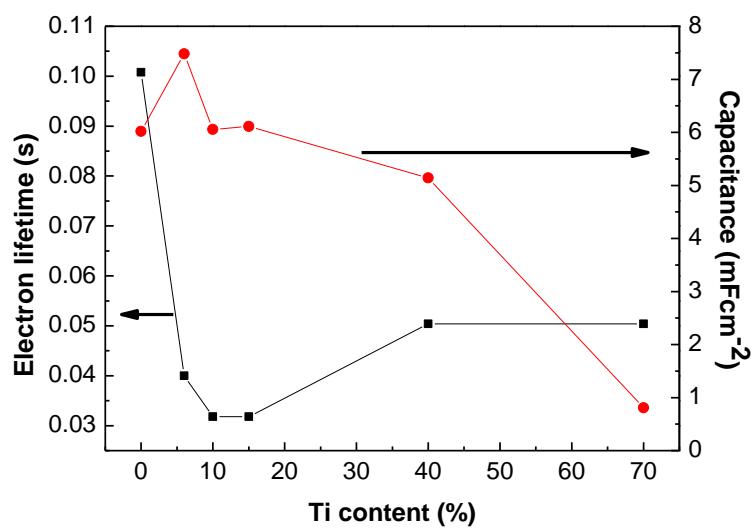


Figure S4. The electron lifetime of DSSCs and capacitance of $\text{Ti}_x\text{Sn}_{1-x}\text{O}_2$ photoanodes measure by EIS.

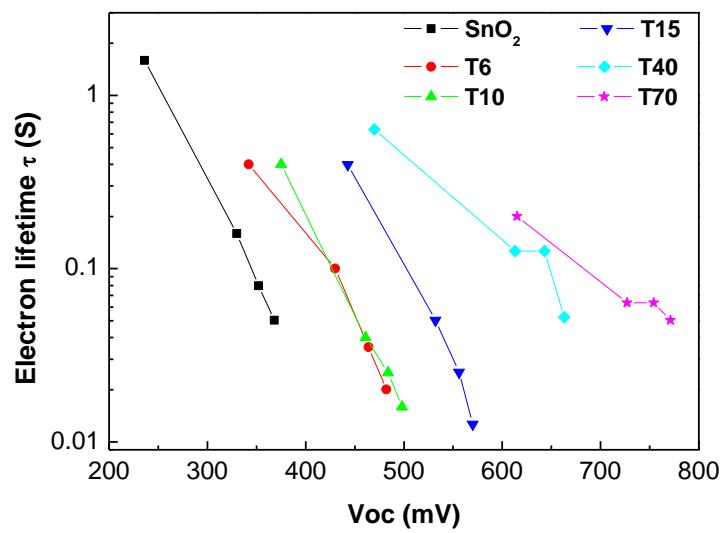


Figure S5. The variation of electron lifetime with photovoltage of DSSCs under different light intensities.

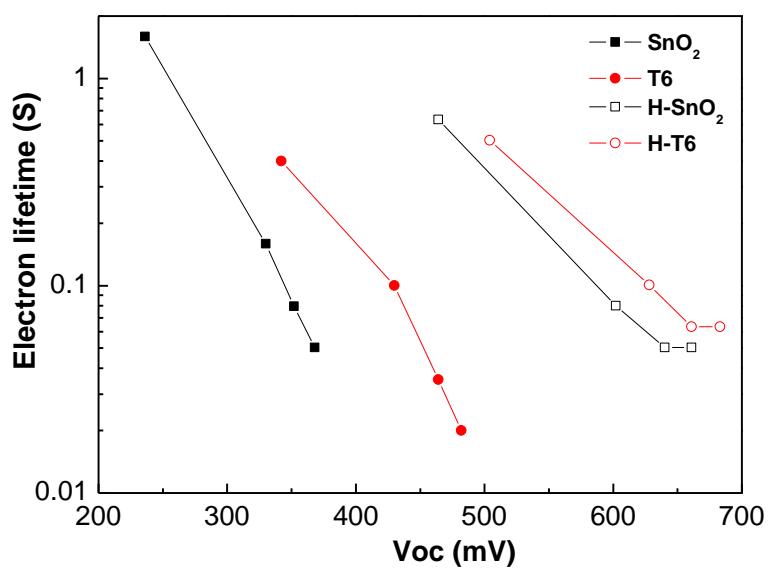


Figure S6. The electron lifetime of SnO_2 , T6, the hybrid photoanode H- SnO_2 and H-T6 under different photovoltages.